

The International Symposium on  
**Optical Science and Technology**

**Noise performance comparison of  
ICCD with CCD and EMCCD cameras**

**Paul Hoess, David Dussault**

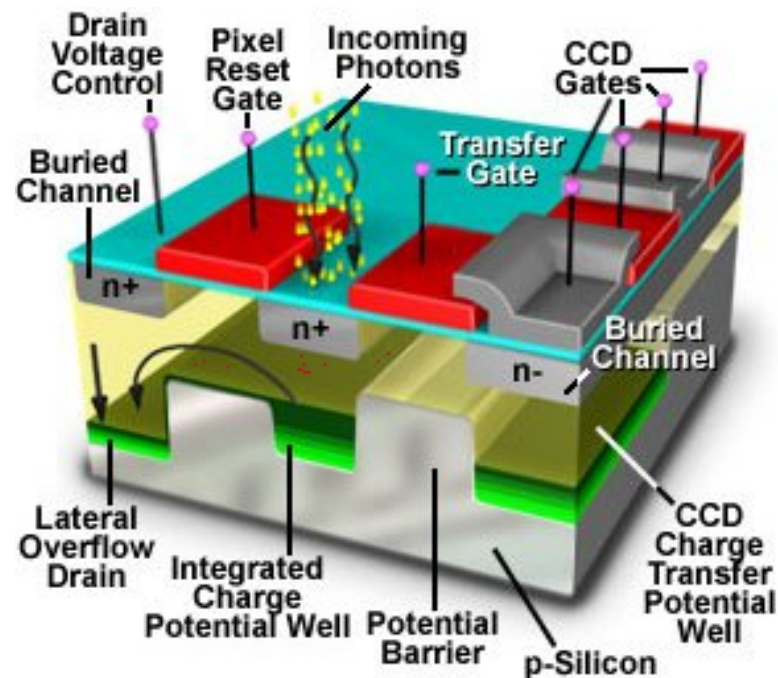
Stanford Computer Optics / Paul Hoess KG, Munich, GERMANY

# Topics

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- **Introduction - 3 LLL sensing concepts**
  - CCD
  - ICCD
  - EMCCD
- **Noise sources**
  - Shot noise
  - Dark current noise
  - Readout noise
- **Signal-to-noise ratio**
  - Single frame operation
  - Long integration time versus frame adding
- **Discussion of the simulation results**
- **Conclusions**

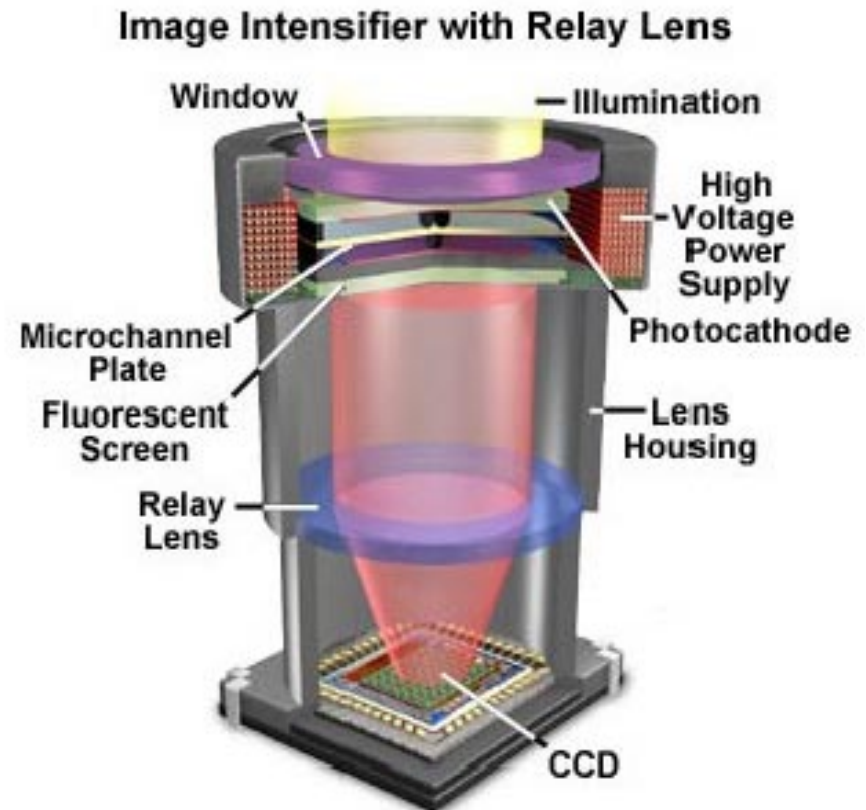
# CCD (Charge-Coupled Device)



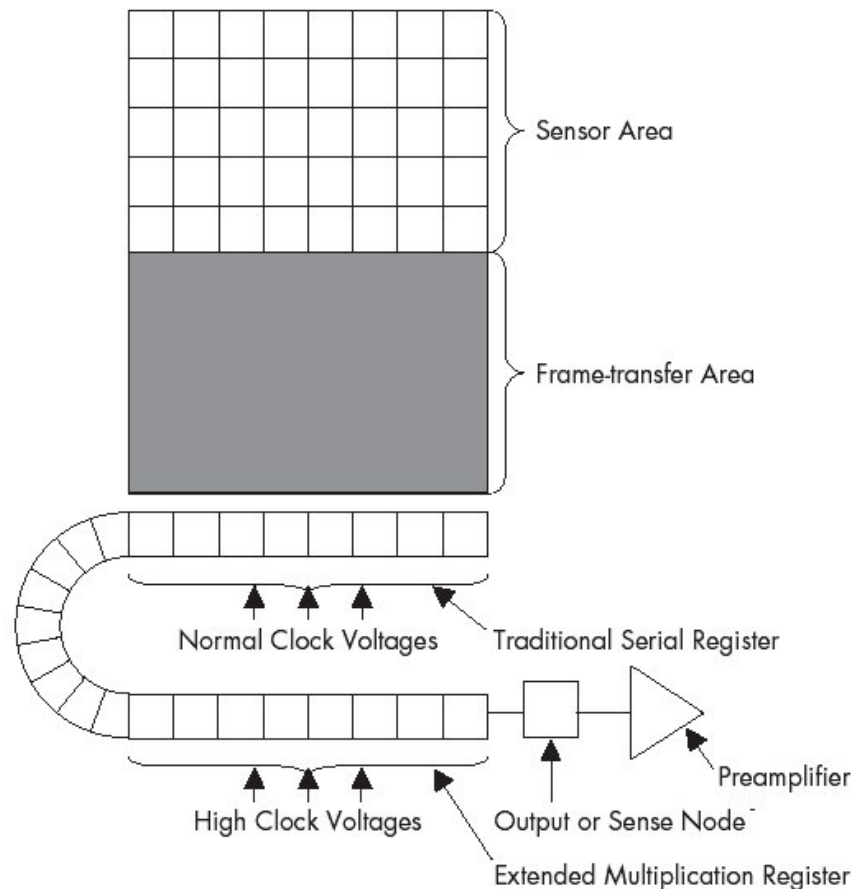
- CCD = array of photodiodes (light-sensitive pixels).
- **Generation** (high Q.E.  $\eta$ ,  $1e^-$  per photon) and **storage** of electrons when exposed to light.
- Read-out of the charge by changing the electrical bias of an adjacent pixel.
- Charge to voltage conversion, digitization to numerical value by external circuitry.

# ICCD (Intensified CCD)

- Photocathode: Generation (low Q.E.  $\eta$ ,  $1e^-$  per  $h\nu$ ) of photoelectrons.
- Microchannel plate (MCP): multiplication ( $G_{MCP}$ ) of electrons.
- Phosphor screen: conversion ( $G_{screen}$ ) of electrons back into highly increased ( $\times 10^4$ - $10^6$ ) number of photons.
- High numerical aperture lens-coupling for superior distortion free image quality.
- CCD: conversion of the very high number of photons to charge, readout and digitization.



# EMCCD (Electron Multiplying CCD)



- Generation and storage of electrons (high Q.E.  $\eta$ ,  $1e^-$  per photon), equivalent to CCD.
- Amplification by impact ionization in the gain register.
- Charge to voltage conversion, digitization equivalent to CCD.

# Noise sources [1]

All signals and noises are calculated in equivalent number of electrons at system output.

- Shot noise  $N_{\text{shot}}$  [ $e^-/\text{pixel}$ ]

$$N_{\text{shot}} = G \times F \times \sqrt{\eta \phi_p \tau}$$

**G**: multiplication gain

**F**: noise factor of gain

$\eta$ : quantum efficiency

$\phi_p$ : mean incident photon flux per pixel

$\tau$ : integration time [s]

# Noise sources [2]

- Dark current and its noise  $N_{dc}$  [e<sup>-</sup>/pixel]

$$N_{dc} = \left[ 2.55 \cdot 10^{15} N_{dc0} \tau \cdot d_{pix}^2 T^{\frac{3}{2}} e^{\left(\frac{-E_g}{2kT}\right)} \right]^{\frac{1}{2}}$$

**$N_{dc0}$** : dark current at room temperature [nA/cm<sup>2</sup>]

**$d_{pix}$** : pixel size [cm]

**T**: operating temperature [K]

**$E_g$** : bandgap energy in eV

**k**: Boltzmann's constant

(8.62 · 10<sup>-5</sup>eV/K)

# Noise sources [3]

- Read-out noise  $N_r$ :
  - generated through charge transfers across the CCD. readout amplifier reset, “any other” electronic noises
  - Strongly pixel clock (frame rate) and slightly temperature dependent.
  - independent of integration time.
  - for EMCCDs:

$$N_r = \left[ N_{r0}^2 + (G \times N_{ct})^2 \right]^{1/2}$$

where  $N_{ct}$  is the charge transfer noise that is multiplied in the gain register and  $N_{r0}$  is all other non-multiplied readout noises.



# Noise sources

- Total noise  $N_{tot}$ :

$$N_{tot} = \left( N_{shot}^2 + N_{dc}^2 + N_r^2 \right)^{1/2}$$

# Signal-to-noise ratio [1]

- Single frame operation

$$SNR_{unit} = \frac{G\eta\phi_p\tau}{(N_{shot}^2 + N_{dc}^2 + N_r^2)^{1/2}}$$

- Shot-noise-limited operation if  $N_r$  and  $N_{dc} \ll N_{shot}$ :
  - high  $\Phi_p$ ,
  - high  $G$ ,
  - or  $N_r$  and  $N_{dc}$  extremely small.

# Signal-to-noise ratio [2]

- Long time integration (traditional approach):

$$SNR_{long} = \frac{n_l G \eta \phi_p \tau}{\left[ n_l (N_{shot}^2 + N_{dc}^2) + N_r^2 \right]^{1/2}} = \sqrt{n_l} \frac{G \eta \phi_p \tau}{\left[ N_{shot}^2 + N_{dc}^2 + (N_r^2 / n_l) \right]^{1/2}}$$

where  $n_l$  is the factor by which the integration time  $\tau$  is increased.



# Parameters of the simulation

## ■ **CCD:**

- $\eta=50\%$ , front-illuminated
- $G=F=1$
- $N_r=25e^-$  (5MHz) or  $5e^-$  (1MHz)

## ■ **ICCD:**

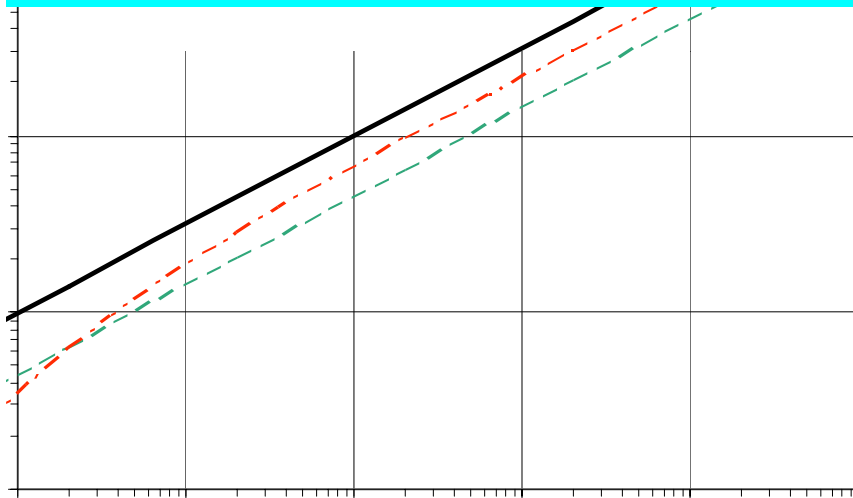
- $\eta=50\%$
- $F=1.6$
- $G=500$
- $N_r=25e^-$

## ■ **EMCCD:**

- $\eta=50\%$  (FI) or  $90\%$  (BI)
- $F=1.4$
- $G=500$
- $N_{r0}=25e^-$
- $N_{ct}=2.2e^-$  (31kHz) or  $5.4e^-$  (1MHz)

- $\tau=20$  ms
- $N_{dc0}=0.1$  or  $3nA/cm^2$  @ 300K

# short frame mode



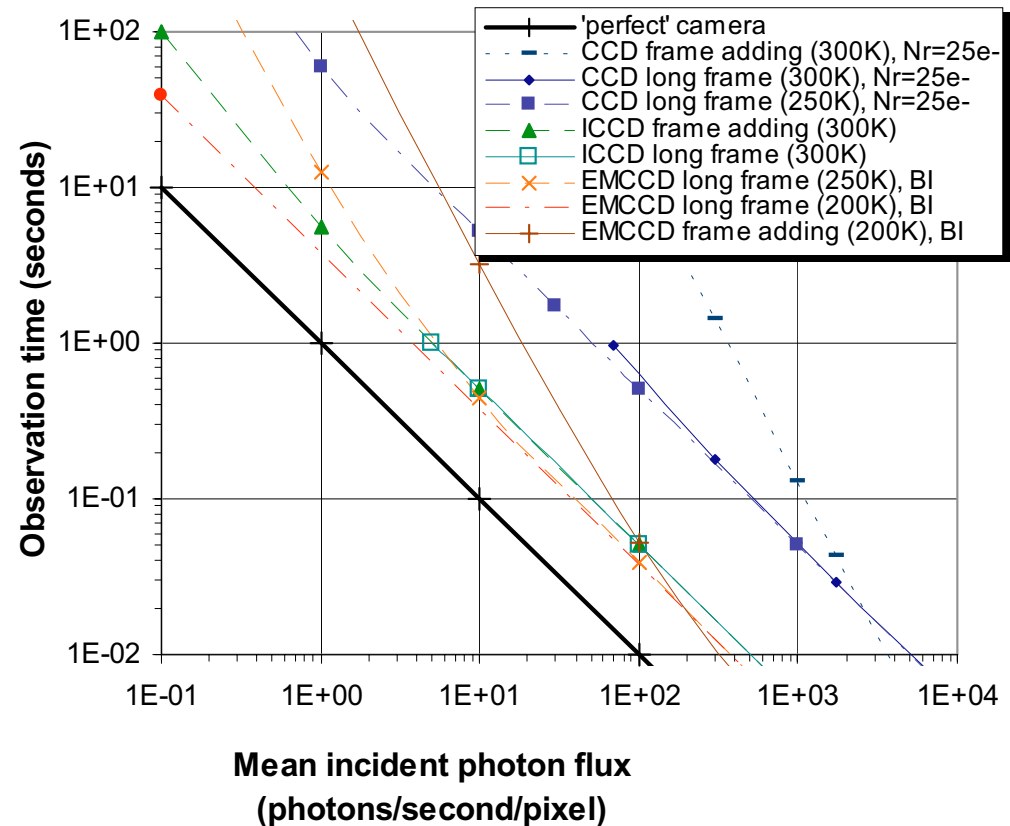
# Simulation of extended integration time

low to very low  $\Phi_p$ , low camera noise

- **CCD:**
  - Better SNR with long frame.
- **EMCCD:**
  - Clear influence of cooling in low light conditions,
  - frame adding not as effective as for ICCD.
- **ICCD:**
  - Same results with frame adding or long frame,
  - cooling not required.

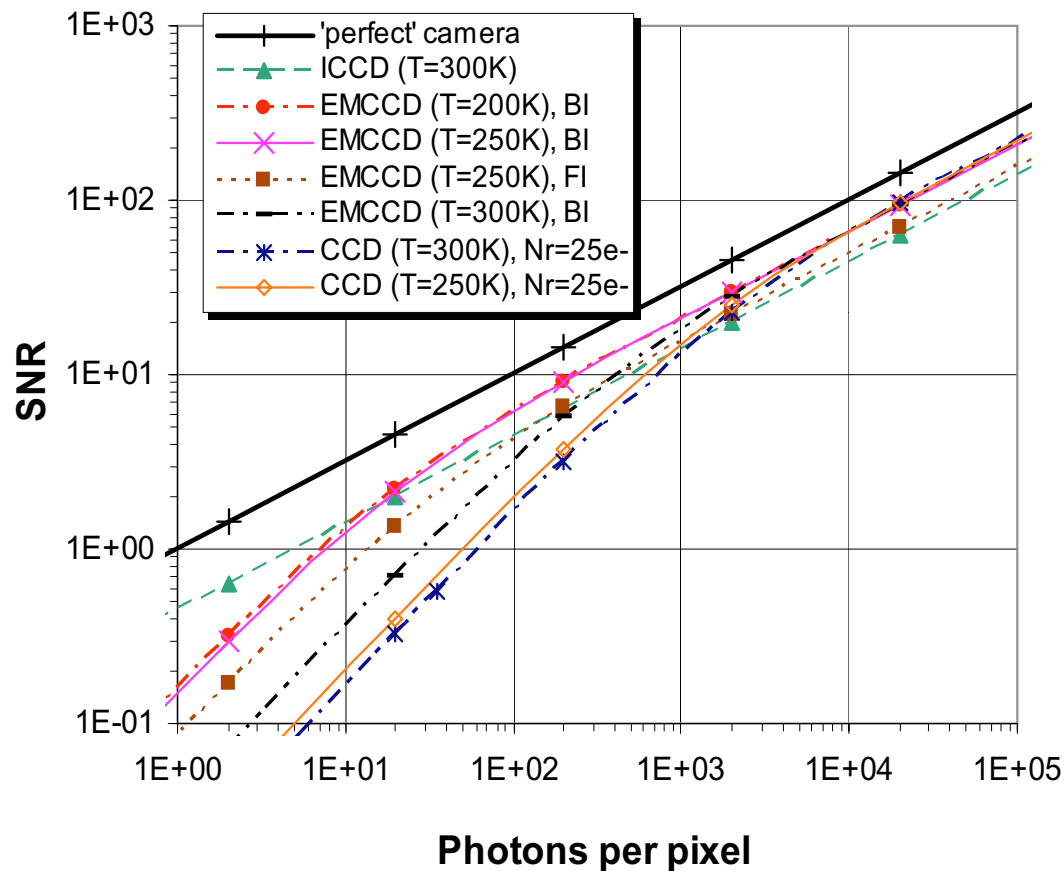
**Parameters:**

- $\tau=20\text{ms}$
- $N_{\text{dc0}}=0.1\text{nA/cm}^2$
- $N_{\text{ct}}=2.2e^-$



# Simulation of single short frame mode

high to medium  $\Phi_p$ , high camera noise, realistic operating conditions



- **CCD:**
  - Negligible temperature influence at 5MHz readout rate.
- **EMCCD:**
  - Still a decrease of the SNR in LLL,
  - Slightly superior to CCD at room temperature,
  - SNR improvement for lower temperatures,
  - BI: high QE, slight temperature dependence, readout dominated.
- **ICCD:**
  - Still in shot-noise-limited operation, unchanged.

**Parameters:**

- $\tau=20\text{ms}$
- $N_{dc0}=3\text{nA/cm}^2$
- $N_{ct}=5.4e^-$



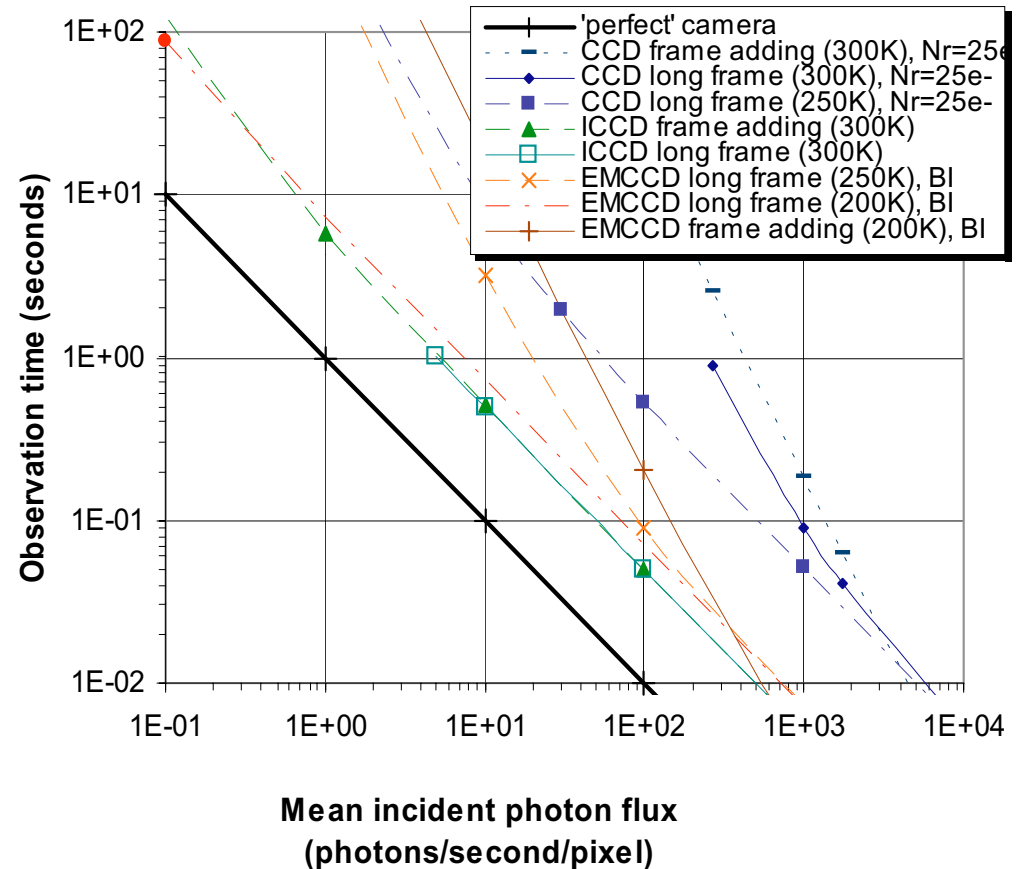
# Simulation of extended integration time

low to very low  $\Phi_p$ , high camera noise, realistic operating conditions

- **CCD:**
  - Long frame better than frame adding,
  - Frame adding: significant sensitivity increase without additional hardware.
- **ICCD:**
  - No influence of noises, better than EMCCD over a wide range.
- **EMCCD:**
  - Better than ICCD only at extremely low light levels (int. time  $\geq$  1min.)

**Parameters:**

- $\tau=20\text{ms}$
- $N_{dc0}=3\text{nA/cm}^2$
- $N_{ct}=5.4e^-$



# Conclusions

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- Best SNR provided by CCD at high light levels, operating range extended to low light levels through slow scan and cooling.
- Need for strong cooling of EMCCD sensors to eliminate dark current.
- Need for very low frame rates operation for EMCCDs in order to minimize charge transfer noise.
- **No cooling, no slow scan required for the CCD sensor of an ICCD system.**